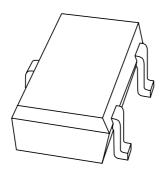
# DISCRETE SEMICONDUCTORS

# DATA SHEET



# **2PD1820A**NPN general purpose transistor

Product data sheet Supersedes data of 1997 May 22 1999 Apr 12



# NPN general purpose transistor

2PD1820A

#### **FEATURES**

- High current (max. 500 mA)
- Low voltage (max. 50 V)
- Low collector-emitter saturation voltage (max. 600 mV).

#### **APPLICATIONS**

• General purpose switching and amplification, especially for portable equipment.

#### **DESCRIPTION**

NPN transistor in an SC-70; SOT323 plastic package. PNP complement: 2PB1219A.

#### **MARKING**

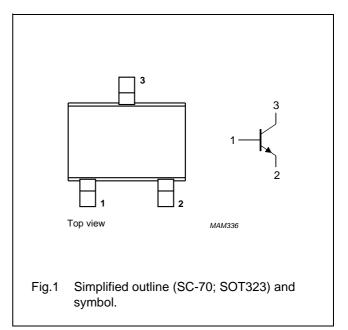
| TYPE NUMBER | MARKING CODE(1) |
|-------------|-----------------|
| 2PD1820AQ   | A*Q             |
| 2PD1820AR   | A*R             |
| 2PD1820AS   | A*S             |

#### Note

\* = - : Made in Hong Kong.
 \* = t : Made in Malaysia.

#### **PINNING**

| PIN | DESCRIPTION |  |
|-----|-------------|--|
| 1   | base        |  |
| 2   | emitter     |  |
| 3   | collector   |  |



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL           | PARAMETER                     | CONDITIONS                       | MIN. | MAX. | UNIT     |
|------------------|-------------------------------|----------------------------------|------|------|----------|
| V <sub>CBO</sub> | collector-base voltage        | open emitter                     | -    | 60   | V        |
| $V_{CEO}$        | collector-emitter voltage     | open base                        | -    | 50   | V        |
| $V_{EBO}$        | emitter-base voltage          | open collector                   | _    | 5    | <b>V</b> |
| I <sub>C</sub>   | collector current (DC)        |                                  | -    | 500  | mA       |
| I <sub>CM</sub>  | peak collector current        |                                  | -    | 1    | Α        |
| $I_{BM}$         | peak base current             |                                  | _    | 200  | mA       |
| P <sub>tot</sub> | total power dissipation       | T <sub>amb</sub> ≤ 25 °C; note 1 | -    | 200  | mW       |
| T <sub>stg</sub> | storage temperature           |                                  | -65  | +150 | °C       |
| Tj               | junction temperature          |                                  | -    | 150  | °C       |
| T <sub>amb</sub> | operating ambient temperature |                                  | -65  | +150 | °C       |

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

# NPN general purpose transistor

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#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                                   | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R <sub>th j-a</sub> | thermal resistance from junction to ambient | note 1     | 625   | K/W  |

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

| SYMBOL             | PARAMETER                            | CONDITIONS   | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|
| I <sub>CBO</sub>   | collector cut-off current            | I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V                                   | _    | 10   | nA   |
|                    |                                      | I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V; T <sub>j</sub> = 150 °C          | _    | 5    | μΑ   |
| I <sub>EBO</sub>   | emitter cut-off current              | I <sub>C</sub> = 0; V <sub>EB</sub> = 4 V                                    | _    | 10   | nA   |
| h <sub>FE</sub>    | DC current gain                      | I <sub>C</sub> = 150 mA; V <sub>CE</sub> = 10 V; note 1                      |      |      |      |
|                    | 2PD1820AQ                            |  | 85   | 170  |      |
|                    | 2PD1820AR                            |  | 120  | 240  |      |
|                    | 2PD1820AS                            |  | 170  | 340  |      |
| h <sub>FE</sub>    | DC current gain                      | I <sub>C</sub> = 500 mA; V <sub>CE</sub> = 10 V; note 1                      | 40   | _    |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | I <sub>C</sub> = 300 mA; I <sub>B</sub> = 30 mA; note 1                      | _    | 600  | mV   |
| C <sub>c</sub>     | collector capacitance                | $I_E = i_e = 0$ ; $V_{CB} = 10 \text{ V}$ ; $f = 1 \text{ MHz}$              | _    | 15   | pF   |
| f <sub>T</sub>     | transition frequency                 | $I_C = 50 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz};$<br>note 1 | 150  | _    | MHz  |

#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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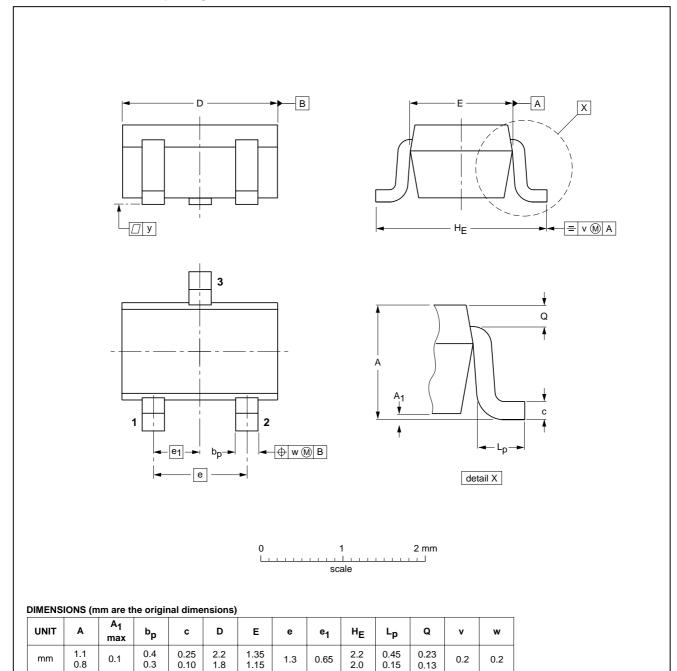
# NPN general purpose transistor

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#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

**SOT323** 



| OUTLINE | REFERENCES |       |       | EUROPEAN | ISSUE DATE |            |
|---------|------------|-------|-------|----------|------------|------------|
| VERSION | IEC        | JEDEC | EIAJ  |          | PROJECTION | ISSUE DATE |
| SOT323  |            |       | SC-70 |          |            | 97-02-28   |

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### NPN general purpose transistor

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#### **DATA SHEET STATUS**

| DOCUMENT<br>STATUS <sup>(1)</sup> | PRODUCT<br>STATUS <sup>(2)</sup> | DEFINITION  |
|-----------------------------------|----------------------------------|---|
| Objective data sheet              | Development                      | This document contains data from the objective specification for product development. |
| Preliminary data sheet            | Qualification                    | This document contains data from the preliminary specification.                       |
| Product data sheet                | Production                       | This document contains the product specification.                                     |

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